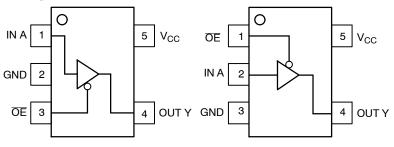
Bus Buffer with 3-State Output

The NL17SG125 MiniGate[™] is an advanced high-speed CMOS Bus Buffer with 3-State Output in ultra-small footprint.

The NL17SG125 input structures provides protection when voltages up to 4.6 V are applied.

Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: t_{PD} = 2.4 ns (Typ) at V_{CC} = 3.0 V, C_L = 15 pF
- Low Power Dissipation: $I_{CC} = 0.5 \ \mu A$ (Max) at $T_A = 25^{\circ}C$
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant





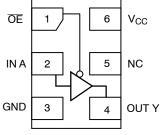
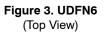


Figure 2. SC-88A (Top View)



Figure 4. Logic Symbol



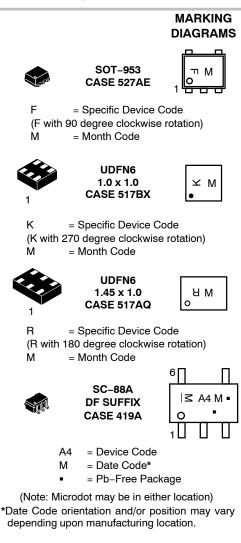
PIN ASSIGNMENT

Pin Number	SOT-953	SC-88A	UDFN6
1	IN A	ŌE	ŌE
2	GND	IN A	IN A
3	ŌE	GND	GND
4	OUT Y	OUT Y	OUT Y
5	V _{CC}	V _{CC}	NC
6			V _{CC}



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FUNCTION TABLE

A Input	OE Input	Y Output
L	L	L
н	L	н
X	н	z

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

MAXIMUM RATINGS

Symbol	Р	arameter	Value	Unit	
V _{CC}	DC Supply Voltage		–0.5 to +5.5	V	
V _{IN}	DC Input Voltage		-0.5 to +4.6	V	
V _{OUT}	DC Output Voltage	Output at High or Low State Power–Down Mode ($V_{CC} = 0 V$)	-0.5 to V _{CC} +0.5 -0.5 to +4.6	V	
I _{IK}	DC Input Diode Current	V _{IN} < GND	-20	mA	
Ι _{ΟΚ}	DC Output Diode Current	V _{OUT} < GND	-20	mA	
I _{OUT}	DC Output Source/Sink Current		±20	mA	
I _{CC}	DC Supply Current per Supply Pin		±20	mA	
I _{GND}	DC Ground Current per Ground Pin		±20	mA	
T _{STG}	Storage Temperature Range		-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case fo	r 10 Seconds	260	°C	
ТJ	Junction Temperature Under Bias		+150	°C	
MSL	Moisture Sensitivity		Level 1		
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in		
V_{ESD}	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3)	>2000 >100	V	
I _{LATCHUP}	Latchup Performance	Above V _{CC} and Below GND at 125°C (Note 4)	±100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

Tested to EIA/JESD22–A114–A.
 Tested to EIA/JESD22–A115–A.

4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage	0.9	3.6	V
V _{IN}	Digital Input Voltage	0.0	3.6	V
V _{OUT}	Output Voltage Output at High or Low State Power-Down Mode (V _{CC} = 0		V _{CC} 3.6	V
T _A	Operating Temperature Range	-55	+125	°C
Δt / ΔV	Input Transition Rise or Fail Rate V_{CC} = 3.3 V ± 0.3	3 V 0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

NL17SG125

DC ELECTRICAL CHARACTERISTICS

					T _A =	25°C	T⊿ 55°C to-	. = 0 +125°C	
Symbol	Parameter	C	onditions	V _{CC} (V)	Min	Max	Min	Max	Uni
V _{IH}	High-Level Input			0.9	V _{CC}		V _{CC}		V
	Voltage			1.1 to 1.3	0.7xV _{CC}		0.7xV _{CC}		
				1.4 to 1.6	$0.65 \mathrm{xV}_{\mathrm{CC}}$		$0.65 \mathrm{xV}_{\mathrm{CC}}$		
				1.65 to 1.95	$0.65 \mathrm{xV}_{\mathrm{CC}}$		$0.65 \mathrm{xV}_{\mathrm{CC}}$		1
				2.3 to 2.7	1.7		1.7		
				3.0 to 3.6	2.0		2.0		
VIL	Low-Level Input			0.9		GND		GND	V
	Voltage			1.1 to 1.3		0.3xV _{CC}		0.3xV _{CC}	
				1.4 to 1.6		0.35xV _{CC}		0.35xV _{CC}	
				1.65 to 1.95		0.35xV _{CC}		0.35xV _{CC}	
				2.3 to 2.7		0.7		0.7	
				3.0 to 3.6		0.8		0.8	
V _{OH}	High-Level	V _{IN} =	I _{OH} = -20 μA	0.9	0.75		0.75		V
	Output Voltage	V _{IH} or V _{IL}	I _{OH} = -0.3 mA	1.1 to 1.3	$0.75 \mathrm{xV}_{\mathrm{CC}}$		$0.75 \mathrm{xV}_{\mathrm{CC}}$		
			I _{OH} = -1.7 mA	1.4 to 1.6	$0.75 \mathrm{xV}_{\mathrm{CC}}$		$0.75 \mathrm{xV}_{\mathrm{CC}}$		
			I _{OH} = -3.0 mA	1.65 to 1.95	Vcc-0.45		Vcc-0.45		
			I _{OH} = -4.0 mA	2.3 to 2.7	2.0		2.0		
			I _{OH} = -8.0 mA	3.0 to 3.6	2.48		2.48		
V _{OL}	Low-Level	V _{IN} =	I _{OL} = 20 μA	0.9		0.1		0.1	V
	Output Voltage	V _{IH} or V _{IL}	I _{OL} = 0.3 mA	1.1 to 1.3		$0.25 \mathrm{xV}_{\mathrm{CC}}$		0.25xV _{CC}	
			I _{OL} = 1.7 mA	1.4 to 1.6		$0.25 \mathrm{xV}_{\mathrm{CC}}$		0.25xV _{CC}	
			I _{OL} = 3.0 mA	1.65 to 1.95		0.45		0.45	
			I _{OL} = 4.0 mA	2.3 to 2.7		0.4		0.4	
			I _{OL} = 8.0 mA	3.0 to 3.6		0.4		0.4	
I _{IN}	Input Leakage Current	0 ≤	$V_{IN} \leq 3.6 V$	0 to 3.6		±0.1		±1.0	μA
I _{CC}	Quiescent Supply Current	V _{IN} =	V _{CC} or GND	3.6		1.0		10.0	μΑ
I _{OZ}	3-State Output Leakage Current	V _{IN} V _{OUT}	= V _{IH} or V _{IL} = 0 to 3.6 V	0.9 to 3.6		1.0		10.0	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NL17SG125

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

					T _A = 25 °C	2		∖ = o +125°C		
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Min	Мах	Unit	
t _{PLH} ,	Propagation Delay,	C _L = 10 pF,	0.9	-	11.3	13.6	-	15.9	ns	
t _{PHL}	A to Y	$R_L = 1 M\Omega$	1.1 to 1.3	-	8.3	10.4	-	12.8		
			1.4 to 1.6	-	5.0	8.5	-	10.0		
			1.65 to 1.95	-	4.0	6.2	-	6.7		
			2.3 to 2.7	-	2.6	3.9	-	4.4		
			3.0 to 3.6	-	2.1	3.1	-	3.7		
		C _L = 15 pF,	0.9	-	12.6	14.7	-	17.0	ns	
		$R_L = 1 M\Omega$	1.1 to 1.3	-	9.6	11.5	-	15.2		
			1.4 to 1.6	-	5.6	9.3	-	11.2		
			1.65 to 1.95	-	4.5	6.9	-	7.1		
			2.3 to 2.7	-	2.9	4.4	-	5.0		
			3.0 to 3.6	-	2.4	3.4	-	3.9		
		C _L = 30 pF,	0.9	-	14.5	16.3	-	19.6	ns	
		$R_L = 1 M\Omega$	1.1 to 1.3	-	11.3	13.6	-	17.5		
			1.4 to 1.6	-	8.2	13.1	-	15.9		
				1.65 to 1.95	-	6	9.2	-	9.6	
				2.3 to 2.7	-	4	5.7	-	6.1	
			3.0 to 3.6	-	3.3	4.4	-	4.8		
t _{PZH} ,	Output Enable Time,	C _L = 10 pF;							ns	
t _{PZL}	OE to Y	$R_L = 100 \text{ k}\Omega$	0.9	-	11.0	13.3	-	15.8		
		$R_L = 5 \ k\Omega$	1.1 to 1.3	-	8.4	10.9	-	13.0		
		$R_L = 5 \ k\Omega$	1.4 to 1.6	-	5.3	7.8	-	8.3		
		$R_L = 5 \ k\Omega$	1.65 to 1.95	-	3.9	5.5	-	5.9		
		$R_L = 5 k\Omega$	2.3 to 2.7	-	2.5	3.5	-	3.8		
		$R_L = 5 k\Omega$	3.0 to 3.6	-	2.1	2.7	-	3		
		C _L = 15 pF;							ns	
		$R_L = 100 \ k\Omega$	0.9	-	12.0	14.8	-	17.0		
		$R_L = 5 k\Omega$	1.1 to 1.3	-	9.0	11.7	-	13.8		
		$R_L = 5 k\Omega$	1.4 to 1.6	-	5.9	8.9	-	11		
		$R_L = 5 k\Omega$	1.65 to 1.95	-	4.4	6.3	-	6.5		
		$R_L = 5 k\Omega$	2.3 to 2.7	-	2.9	3.9	-	4.2		
		$R_L = 5 k\Omega$	3.0 to 3.6	-	2.3	3	-	3.3		
		C _L = 30 pF;							ns	
		R_L = 100 k Ω	0.9	-	13.0	15.2	-	18.3	1	
		$R_L = 5 k\Omega$	1.1 to 1.3	-	10.0	13.1	-	15.2	1	
		$R_L = 5 k\Omega$	1.4 to 1.6	-	8.3	12.2	-	13.7	1	
		$R_L = 5 k\Omega$	1.65 to 1.95	-	6.1	8.6	-	9.7	1	
		$R_L = 5 k\Omega$	2.3 to 2.7	-	3.8	5	-	5.5		
		$R_L = 5 k\Omega$	3.0 to 3.6	-	2.9	3.8	-	4.2		

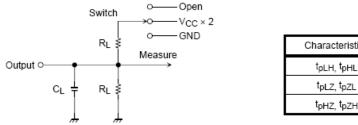
NL17SG125

					T _A = 25 °(Τ _Δ -55°C to	. = 9 +125°C	
Symbol	Parameter	Test Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _{PHZ} ,	Output Disable Time, OE to Y	C _L = 10 pF;							ns
t _{PLZ}	UE IO Y	R_L = 100 k Ω	0.9	-	100.4	-	-	-	
		$R_L = 5 \ k\Omega$	1.1 to 1.3	-	9.1	14.4	-	22.4	
		$R_L = 5 \ k\Omega$	1.4 to 1.6	-	7.1	9.1	-	10.4	1
		$R_L = 5 \ k\Omega$	1.65 to 1.95	-	6.5	8.3	-	9	1
		$R_L = 5 \ k\Omega$	2.3 to 2.7	-	5.8	7.3	-	8.8	
		$R_L = 5 \ k\Omega$	3.0 to 3.6	-	5.4	6.9	-	7.6	
		C _L = 15 pF;							ns
		R_L = 100 k Ω	0.9	-	122.2	-	-	-	
		$R_L = 5 \ k\Omega$	1.1 to 1.3	-	9.8	15.3	-	25.1	
		$R_L = 5 \ k\Omega$	1.4 to 1.6	-	7.8	9.8	-	11.3	1
		$R_L = 5 \ k\Omega$	1.65 to 1.95	-	7.2	9.2	-	10.6	1
		$R_L = 5 \ k\Omega$	2.3 to 2.7	-	7	8.2	-	10.3	
		$R_L = 5 \ k\Omega$	3.0 to 3.6	-	6.6	7.7	-	9.5	1
		C _L = 30 pF;							ns
		$R_L = 100 \ k\Omega$	0.9	-	217.1	-	-	-	1
		$R_L = 5 \ k\Omega$	1.1 to 1.3	-	13.2	19.6	-	31.9	1
		$R_L = 5 \ k\Omega$	1.4 to 1.6	-	12.2	13.5	-	14.9	1
		$R_L = 5 \ k\Omega$	1.65 to 1.95	-	11.4	12.7	-	13.9	1
		$R_L = 5 \ k\Omega$	2.3 to 2.7	-	11.3	12.2	-	13.5]
		$R_L = 5 \ k\Omega$	3.0 to 3.6	-	10.2	11.5	-	12.9]
C _{IN}	Input Capacitance		0 to 3.6		3	-	-	-	pF
CO	Output Capacitance	V _O = GND	0		3	-	-	-	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	f = 10 MHz	0.9 to 3.6	-	4	-	-	-	pF

AC ELECTRICAL CHARACTERISTICS (Input tr = tf = 3.0 ns) (continued)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

performance may not be indicated by the Electrical Characteristics if operated under different conditions.
C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no-load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.



Characteristics	Switch
^t pLH, ^t pHL	Open
tpLZ, tpZL	$V_{CC} \times 2$
tpHZ, tpZH	GND



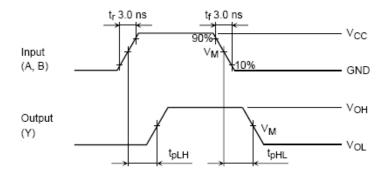


Figure 6. t_{PLH}, t_{PHL} Waveforms

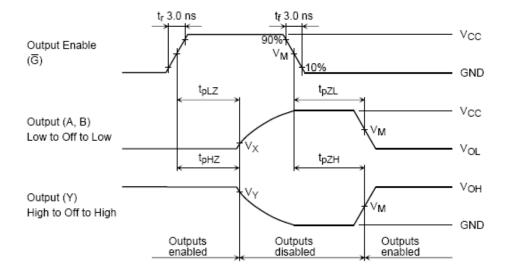


Figure 7. t_{PLZ} , t_{PHZ} , t_{PZH} , t_{PZL} Waveforms

ORDERING INFORMATION

Device	Package	Shipping [†]
NL17SG125P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel
NL17SG125DFT2G	SC-88A (Pb-Free)	3000 / Tape & Reel
NLV17SG125DFT2G*	SC-88A (Pb-Free)	3000 / Tape & Reel
NL17SG125MU1TCG**	UDFN6 1.45 x 1 mm (Pb-Free)	3000 / Tape & Reel
NL17SG125MU3TCG**	UDFN6 1 x 1 mm (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

**In Development

MiniGate is a trademark of Semiconductor Components Industries, LLC (SCILLC).

NSEM



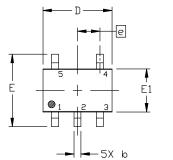
SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

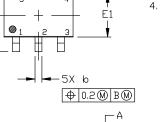
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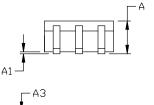
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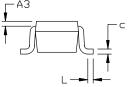
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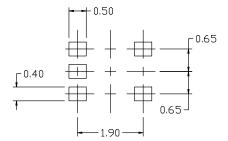
DATE 11 APR 2023











RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
MIU	MIN.	NDM.	MAX.		
A	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
С	0.10		0.25		
D	1.80	2.00	5'50		
E	2.00	2.10	5'50		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

GENERIC MARKING





*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
DOCUMENT NUMBER:	98ASB42984B			ot when accessed directly from when stamped "CONTROLLED (
DESCRIPTION:	SC-88A (SC-70-	5/SOT-353)			PAGE 1 OF 1

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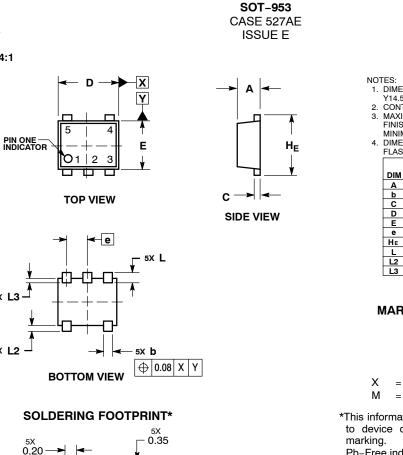
5X L3

5X L2

PACKAGE OUTLINE

0.35 PITCH





DATE 02 AUG 2011

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS				
DIM	MIN	NOM	MAX		
Α	0.34	0.37	0.40		
b	0.10	0.15	0.20		
С	0.07	0.12	0.17		
D	0.95	1.00	1.05		
E	0.75	0.80	0.85		
е		0.35 BS	С		
ΗE	0.95	1.00	1.05		
L		0.175 RE	F		
L2	0.05	0.10	0.15		
L3			0.15		

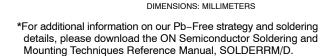
GENERIC **MARKING DIAGRAM***

= Specific Device Code

= Month Code

*This information is generic. Please refer to device data sheet for actual part

Pb-Free indicator, "G" or microdot " .", may or may not be present.



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